



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Charles H. Dennison § Group Art Unit: 2811
Serial No.: 10/633,886 §
Filed: August 4, 2003 § Examiner: Steven Loke
For: Damascene Conductive Line § Atty. Dkt. No.: ITO.0544US
 For Contacting An Underlying § (P15589)
 Memory Element §

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Applicant submits the references listed on the attached form PTO 1449, copies of which are enclosed. A copy of a communication dated December 14, 2004 from a foreign patent office in a counterpart application is also enclosed. I, the undersigned, hereby certify that each item of information contained in the Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement. Please apply any charges or credits to Deposit Account No. 20-1504 (ITO.0544US).

Respectfully submitted,

Trop

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January 18, 2005

Date

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I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as **first class mail** with sufficient postage on the date indicated above and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Monica Jacobs
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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

JAN 2 1 2005

ATTY DOCKET NO.
ITO.0544US (P15589)SERIAL NO.
10/633,886

APPLICANT(S):

CHARLES H. DENNISON

FILING DATE:

August 4, 2003

GROUP ART UNIT:

2811

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
A.	5,970,336	10/19/1999	Wolstenholme et al.			
B.	6,567,293	05/20/2003	Lowrey et al.			
C.						
D.						
E.						
F.						
G.						
H.						

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
I.	DD 251 225 A1	11/04/1987	Dutch				
J.	WO 2004/090984	10/21/2004	PCT				
K.							
L.							
M.							
N.							
O.							

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

P.	Horii, H., Yi, J.H., Park, J.H., Ha, Y.H., Baek, I.G., Park, S.O., Hwang, Y.N., Lee, S.H., Kim, Y.T., Lee, K.H., Chung, U-In and Moon, J.T., "A Novel Cell Technology Using N-doped GeSbTe Films for Phase Change RAM," presented at IEEE 2003 Symposium on VLSI Technology, Kyoto, Japan, June 12-14, 2003
Q.	
R.	
S.	
T.	

EXAMINER

DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.